"Semiconductor Memory Device Having Multi-layered Storage Node Contact Plug And Method For Fabricating the Same"

Serial No. (New) - Attny. Doc. No. SEC.872D

Inventors: Beom-jun JIN et al.

FIG. 1

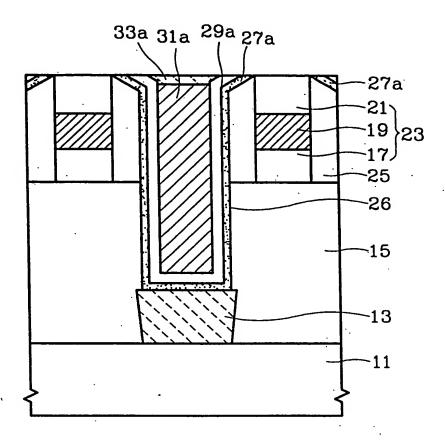
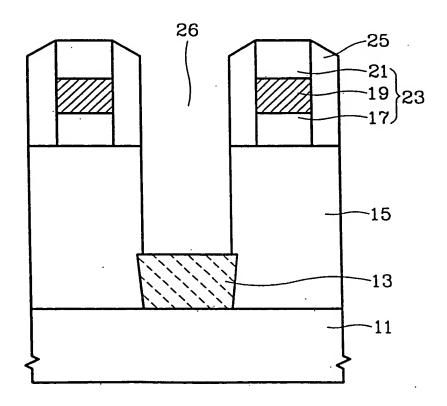


FIG. 2



"Semiconductor Memory Device Having Multi-layered Storage Node Contact Plug And Method For Fabricating the Same"

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FIG. 3

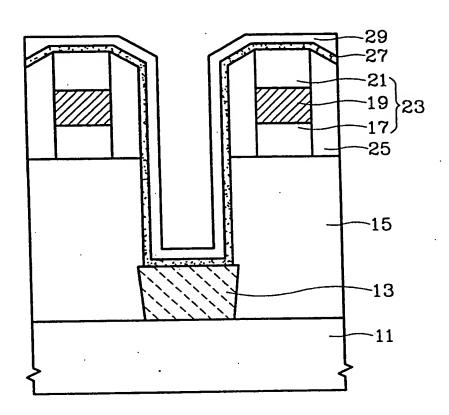
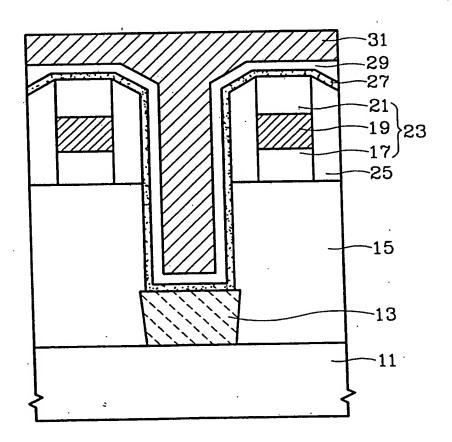


FIG. 4



"Semiconductor Memory Device Having Multi-layered Storage Node Contact Plug And Method For Fabricating the Same" Serial No. (New) - Attny. Doc. No. SEC.872D Inventors: Beom-jun JIN et al.

FIG. 5

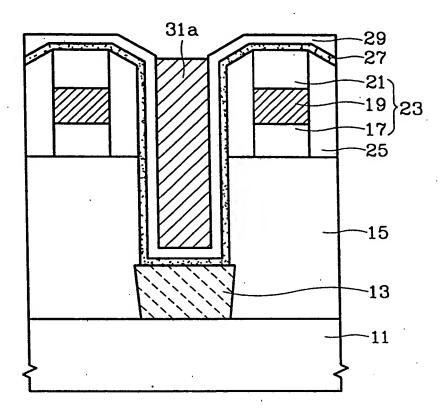


FIG. 6

